Notice of Allowability	Application No.	Applicant(s)
	10/698,884	HAIGHT ET AL.
	Examiner	Art Unit
	Marianne L. Padgett	1762
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to <u>Board decision of 12/1/2006</u> .		
2. The allowed claim(s) is/are <u>1-25</u> .		
3.		
Attachment(s)  1. ☑ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☐ Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date  4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	5. ☐ Notice of Informal P 6. ☐ Interview Summary Paper No./Mail Dat 7. ☐ Examiner's Amendn 8. ☑ Examiner's Stateme 9. ☐ Other	(PTO-413), te

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1. The following is an examiner's statement of reasons for allowance: see Board decision.

Up date of prior art & review of references from other subclasses directed towards irradiation + deposition, not necessarily from vapor, found no more relevant prior art. The reference to Hacker et al. (4,948,629) is cited as of interest as it employs a pulsed excimer laser to deposit diamond from vaporized organic compounds in a carrier gas via a technique where deposition occurs in locations where the laser strikes substrate & the deposition is initiated by photo dissociation via the excimer laser (col. 1, lines 31-col. 2, line 5 & example 2; especially noting col. 1, lines 65-68 & col. 2, lines 34-36), however the disclosure of this patent provides insufficient information to determine the precise mechanism, i.e. whether the photo dissociation is occurring in the gas above the deposition site, or on the substrate after condensation of the organic compound, hence whether or not it reads on the claimed invention. It is noted that discussion in Ziv et al. (5,060,595, previously cited in IDS; col. 5, lines 8-27, especially 16-18) suggests that photolytic mechanisms are generally in the gas phase, while laser reactions induced by surface effects are generally pyrolytic mechanisms, but these conclusions cannot be necessarily applied to nor excluded from the Hacker et al. teachings, hence Hacker et al. can only said to be of interest.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

2. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Marianne L. Padgett whose telephone number is (571) 272-1425. The examiner can normally be reached on M-F from about 8:30 a.m. to 4:30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy Meeks, can be reached at (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

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Information regarding the status of an application may be obtained from the Patent Application

Information Retrieval (PAIR) system. Status information for published applications may be obtained

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MLP/dictation software

12/5/2006

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